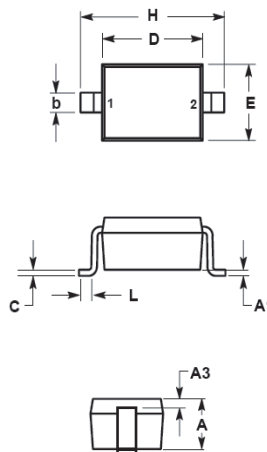


Features

- Fast Switching Speed.
- Surface Mount Package Switching Applications.
- High Conductance.
- Marking Code:T4



SOD-323		
Dim.	Min.	Max.
A	0.80	1.10
A1	0.00	0.10
A3	0.15 REF	
B	0.25	0.40
C	0.10	0.15
D	1.60	1.80
E	1.15	1.35
L	0.20	0.50
H	2.30	2.80
Dimensions in millimeter		

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	V_{RM}	100	V
Reverse Voltage	V_R	75	V
Average Rectified Forward Current	$I_{F(AV)}$	150	mA
Non-repetitive Peak Forward Surge Current at $t = 1\text{ s}$ at $t = 1\text{ }\mu\text{s}$	I_{FSM}	1 2	A
Power Dissipation	P_{tot}	200	mW
Thermal Resistance from Junction to Ambient Air	$R_{\theta JA}$	625	$^\circ\text{C/W}$
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 65 to + 150	$^\circ\text{C}$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 5\text{ }\mu\text{A}$	$V_{(BR)R}$	75	-	V
Forward Voltage at $I_F = 1\text{ mA}$ at $I_F = 10\text{ mA}$ at $I_F = 50\text{ mA}$ at $I_F = 150\text{ mA}$	V_F	- - - -	0.715 0.855 1 1.25	V
Peak Reverse Current at $V_R = 75\text{ V}$ at $V_R = 20\text{ V}$ at $V_R = 75\text{ V}, T_J = 150^\circ\text{C}$ at $V_R = 25\text{ V}, T_J = 150^\circ\text{C}$	I_R	- - - -	1 25 50 30	μA nA μA μA
Total Capacitance at $V_R = 0\text{ V}, f = 1\text{ MHz}$	C_T	-	2	pF
Reverse Recovery Time at $I_F = 10\text{ mA}, I_{rr} = 1\text{ mA}, V_R = 6\text{ V}, R_L = 100\text{ }\Omega$	t_{rr}	-	4	ns



HAICHUANG SEMI

1N4148WS

SURFACE MOUNT FAST SWITCHING DIODE

TYPICAL TRANSIENT CHARACTERISTICS

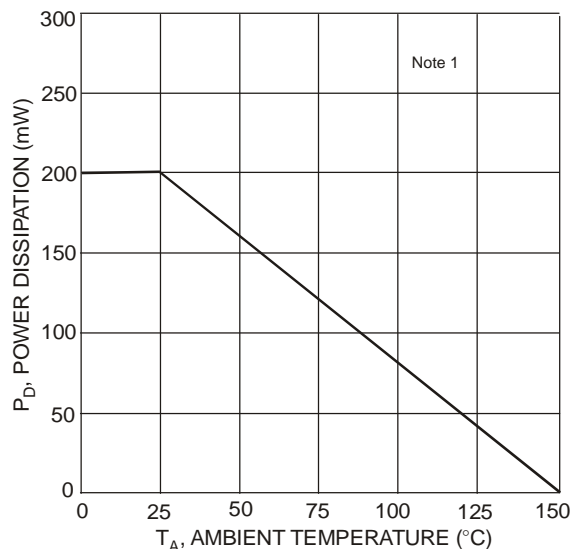


Fig. 1 Power Derating Curve

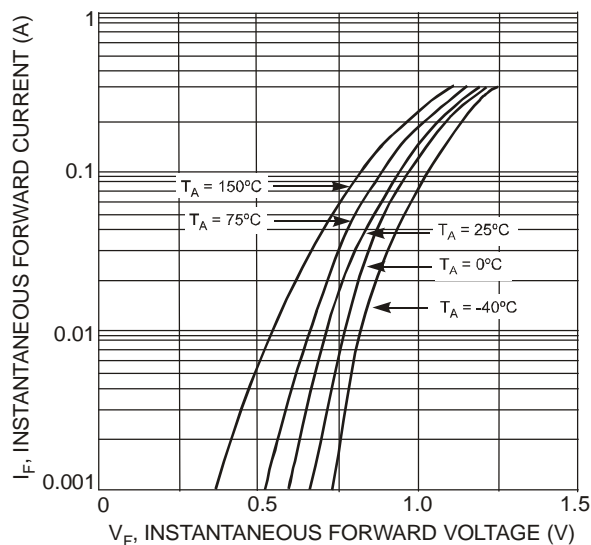


Fig. 2 Typical Forward Characteristics

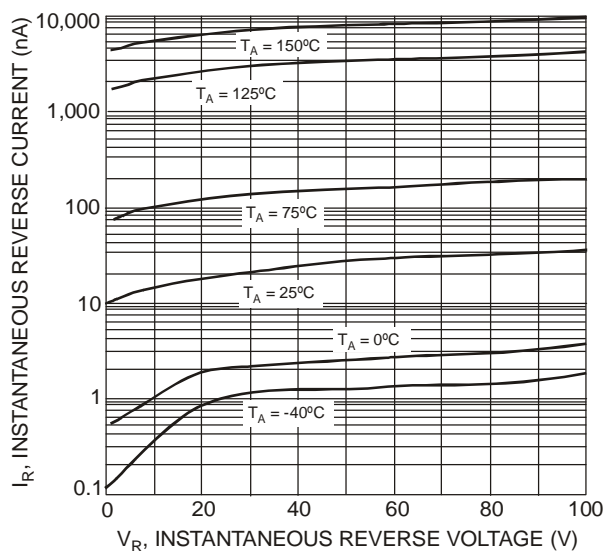


Fig. 3 Typical Reverse Characteristics

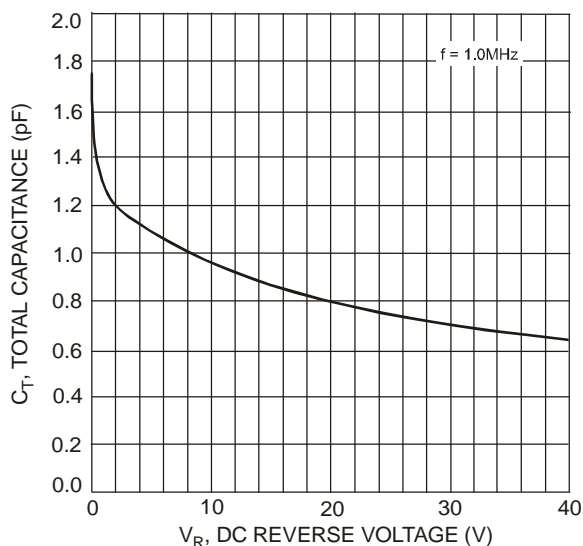


Fig. 4 Total Capacitance vs. Reverse Voltage

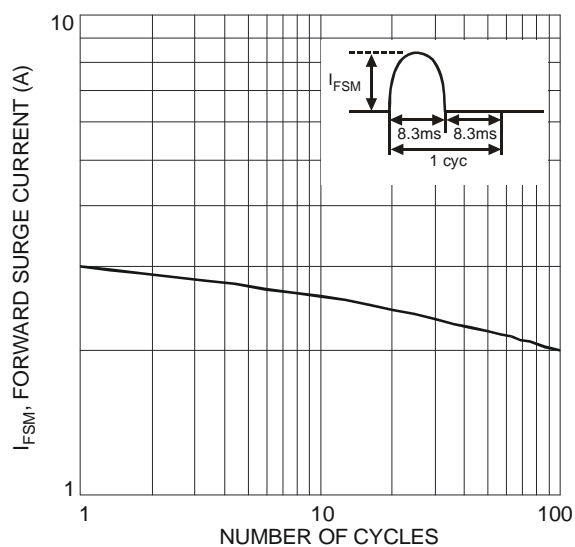


Fig. 5 Maximum Non-Repetitive Surge Current

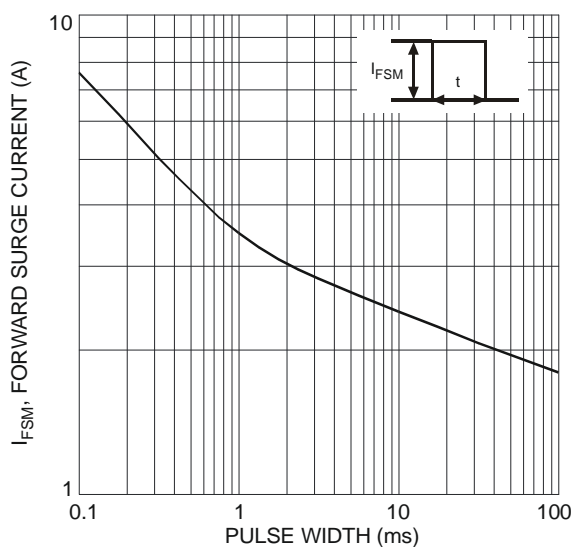


Fig. 6 Maximum Non-Repetitive Surge Current

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